To request any additional information please contact us at:

Email: sales@axcelphotonics.com

Phone: (508) 481-9200

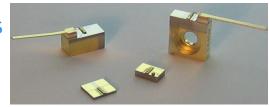


Features

- Up to 3 W CW output power.
- High Quality, Reliability, & Performance

Product Specifications

808nm Multi-Mode Laser Diodes 100µm emitter(1W-3W)



Description:

High brightness, high quality, and high reliability are the foundation of our multi mode product line. Axcel's 808nm multi mode laser diodes are available with up to 3W of continuous output power from a $100\mu m$ single emitter chip. Axcel's trademark laser chip design creates unmeasurable degradation and long lifetimes that make our chips among the most reliable in the industry today. Our 808nm multi mode line serves a broad range of applications including solid state pumping, graphics, medical, dental, industrial, and defense.

Packaging options include industry standard 9mm TO-can, C-mount, B-mount, and QA-mount. More product options are available upon request. Please view our website for mechanical drawings of all of our sub-mount, mount, and module packages.

Applications

- Solid State Pumping
- Graphics
- Medical/Dental
- Industrial
- Defense

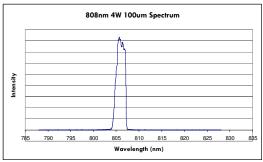
Standard Product Specifications for 808nm Multi-mode Diodes

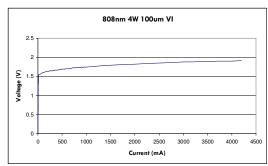
		<u>1W</u>	Serie	<u>es</u>	_	<u>2W</u>	<u>Serie</u>	<u>s</u>	<u>3W</u>	Serie	<u>s</u>
<u>Parameter</u>	<u>Unit</u>	<u>Min</u>	<u>Тур</u>	Max		Min	Тур	<u>Max</u>	Min	Тур	<u>Max</u>
Wavelength	nm	805	808	811		805	808	811	805	808	811
Spectrum FWHM	nm	-	2	4		-	2	4	-	2	4
Operating Power (P _o)	w	-	1.0	-		-	2.0	•	-	3.0	-
Operating Current (I _o)	Α	-	1.1	1.4		-	2.0	2.4	-	2.8	3.2
Operating Voltage (V _o)	٧	-	1.9	2.2		-	1.9	2.2	-	1.9	2.2
Lifetime	hour	10,000	-	-		10,000	•	•	10,000	•	-
Vertical Far Field	deg, FWHM	-	30	35		-	30	35	-	30	35
Parallel Far Field	deg, FWHM	-	8	11		-	8	11	-	8	11
Threshold (I _{th})	Α	-	0.3	0.5		-	0.4	0.6	-	0.4	0.6
Slope Efficiency (dP/dl)	W/A	1.0	1.2	-		1.0	1.2	-	1.0	1.2	-
Storage Temp.	۰C	-40	-	80		-40	•	80	-40	•	80
Operating Temp. (T _{op})	۰C	-20	25	50		-20	25	50	-20	25	50
Lead Soldering Temp.(5 sec)	۰C	-	-	250		-	-	250	-	-	250

Note:

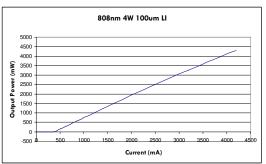
- 1) Specifications are subject to change without notice.
- 2) All Axcel Photonics products are TE polarized

808nm Multi-Mode Product Performance Data Graphs





1W Series



Determining Your Product number:

MM—WWW—PPPP—XYZ—(custom add-ons) (package)-(wavelength)-(power)-(options)

Standard Product Configurations

3W Series

				CM-808-1000-130	CM-808-3000-130
Package:		3000	3W	BM-808-1000-130	BM-808-3000-130
CM	C-mount	X Option (aperture	size)	QA-808-1000-130	C4-808-3000-130
ВМ	B-mount	1	100μm aperture	M9-808-1000-130	
QA	QA-mount	Y Option (waveleng	gth tolerance)	M9-808-1000-13P	
M9	9mm TO-can	3	±3 nm	2W Series	
C4	chip on 4mm submount	Z Option (additiona	l options)	CM-808-2000-130	
<u>Wavelength</u>		0 none		BM-808-2000-130	
808	808nm	P	w/photodiode	QA-808-2000-130	
Power Options:			re our standard product configurations.	M9-808-2000-130	
1000	1W		e available, please inquire about any at you may require when contacting our	M9-808-2000-13P	
2000	2W	Sales Team.			

Safety

Caution: Laser light emitted from any diode laser is invisible and may be harmful to the human eye. Avoid looking directly into the diode laser aperture when the device is in operation.

Note: The use of optical instruments with this product will increase eye hazard.

ESD Caution

Always handle diode lasers with extreme care to prevent electrostatic discharge, the primary cause of unexpected diode failure. You can prevent ESD by always wearing wrist straps, grounding all applicable work surfaces, and following extremely rigorous anti-static techniques when handling diode lasers.

Operating Considerations

Operating the diode laser outside of its maximum ratings may cause device failure or a safety hazard. Power supplies used with the component must be employed such that the maximum peak optical power cannot be exceeded. CW diode lasers may be damaged by excessive drive current or switching transients. When using power supplies, the diode laser should be connected with the main power on and the output voltage at zero. The current should be increased slowly while monitoring the diode laser output power and the drive current. Device degradation accelerates with increased temperature, and therefore careful attention to minimize the case temperature is advised. A proper heat-sink for the diode laser on a thermal radiator will greatly enhance laser life.

Power Output Danger Label



21 CFR 1040.10 Compliance

INVISIBLE LASER RADIATION DIRECT OR SCATTERED RADIATION DIODE LASER 8W MAX OUTPUT at 780-1060 nm CLASS IV LASER PRODUCT







WARNING! Invisible laser radiation is emitted from devices as shown below





Because of the small size of these devices, each of the labels shown are attached to the individual shipping container. They are illustrated here to comply with 21 CFR 1040.10 as applicable under the Radiation Control for Health and Safety Act of 1968.